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## High－／Full－Speed USB 2．0 Switches


#### Abstract

General Description The MAX4906／MAX4906F／MAX4907／MAX4907F analog switches combine the low on－capacitance（CON）and low on－resistance（RON）necessary for high－perfor－ mance switching applications．These devices are designed for USB 2.0 high－speed applications at 480 Mbps ．These switches will also handle all the requirements for USB low－and full－speed signaling． The MAX4906／MAX4906F feature two single－pole／dou－ ble－throw（SPDT）switches，and the MAX4907／ MAX4907F feature two single－pole／single－throw switches （SPST）．The MAX4907／MAX4907F have a low $7 \Omega$（max） on－resistance and 7pF（max）on－capacitance．These devices are fully specified to operate from a single +3.0 V to +3.6 V power supply and are protected against $a+5.5 \mathrm{~V}$ short to COM1 and COM2．This feature makes them fully compliant with the USB 2.0 specification of +5.5 V fault protection．These devices feature a low threshold voltage and a $+1.4 \mathrm{~V} \mathrm{~V}_{\mathrm{IH}}$ ，permitting them to be used with low－voltage logic．The MAX4906／ MAX4906F／MAX4907／MAX4907F operate at $300 \mu A$ （max）quiescent current and feature a shutdown input to reduce the quiescent current to less than $2 \mu \mathrm{~A}$（max）． The MAX4906／MAX4906F／MAX4907／MAX4907F are avail－ able in space－saving， $2 \mathrm{~mm} \times 2 \mathrm{~mm} \mu \mathrm{DFN}$ packages and operate over a $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ temperature range．


Cell Phones
PDAs
Digital Still Cameras
GPS
Notebook Computers
Relay Replacements

Applications<br>USB Switching<br>Ethernet Switching<br>Video Switching<br>Bus Switches<br>T3／E3 Switches for Redundancy Protection

## ＿Typical Operating Characteristics


－Fully Specified for a Single＋3．0V to＋3．6V Power－Supply Voltage
－Low $4 \Omega$（typ）， $7 \Omega$（max）On－Resistance（Ron）
－MAX4907／MAX4907F Ultra－Low 4pF（typ），
7pF（max）On－Capacitance（Con）
－－3dB Bandwidth：1GHz（typ）
－Low Bit－to－Bit Skew $\leq$ 100ps
－Shutdown Input Reduces Power Consumption to $2 \mu \mathrm{~A}$（max）
－3．3V，1．8V，and 1．4V Logic Compatible
－COM＿Analog Inputs Fault Protected Against Shorts to USB Supply Rail Up to +5.5 V
－Space－Saving Packages
8－Pin and $10-\mathrm{Pin}, 2 \mathrm{~mm} \times 2 \mathrm{~mm} \mu \mathrm{DFN}$ Packages

Ordering Information

| PART | PIN－PACKAGE | PKG CODE |
| :--- | :--- | :---: |
| MAX4906ELB | $10 \mu$ DFN | L1022－1 |
| MAX4906FELB | $10 \mu \mathrm{DFN}$ | L1022－1 |
| MAX4907ELA | $8 \mu \mathrm{DFN}$ | L822－1 |
| MAX4907FELA | $8 \mu \mathrm{DFN}$ | L822－1 |

Note：All devices operate over the $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ operating temperature range．

Selector Guide appears at end of data sheet．

Pin Configurations


## High-/Full-Speed USB 2.0 Switches

## ABSOLUTE MAXIMUM RATINGS

Voltages Referenced to GND


| Continuous Power Dissipation ( $\left.\mathrm{T}_{\mathrm{A}}=+70^{\circ} \mathrm{C}\right)$ |  |
| :---: | :---: |
| 8-Pin $\mu$ DFN (derate $5.0 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $+70^{\circ} \mathrm{C}$ ) | 400mW |
| 10-Pin $\mu$ DFN (derate $5.3 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $+70^{\circ} \mathrm{C}$ )...... .423 .7 mW |  |
| Operating Temperature Range | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| Junction Temperature | $+150^{\circ} \mathrm{C}$ |
| Storage Temperature R | + $150^{\circ} \mathrm{C}$ |
| Lead Temperature (soldering, 10s) | $+300^{\circ} \mathrm{C}$ |

Note 1: Signals on IN, SHDN or SHDN/EN exceeding V+ or GND are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ELECTRICAL CHARACTERISTICS

$\left(\mathrm{V}+=+3 \mathrm{~V}\right.$ to $+3.6 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=\mathrm{T}_{\mathrm{MIN}}$ to $\mathrm{T}_{\mathrm{MAX}}$, unless otherwise noted. Typical values are at $\mathrm{V}+=3.3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$.) (Note 2)

| PARAMETER | SYMBOL | CONDITIONS |  | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG SWITCH |  |  |  |  |  |  |  |
| Analog Signal Range | $\mathrm{V}_{\mathrm{COM}}, \mathrm{~V}_{\mathrm{NO}},$ <br> $\mathrm{V}_{\mathrm{NC}}$ _ | SHDN or SHDN/EN $=0($ Note 3) |  | 0 |  | V+ | V |
| Fault-Protection Trip Threshold | VFP |  |  | 3.6 |  | 4.0 | V |
| On-Resistance | Ron | $\begin{aligned} & \mathrm{ICOM}_{-}=-40 \mathrm{~mA}, \\ & O V \leq \mathrm{V}_{\text {COM }} \leq \mathrm{V}+, \\ & \text { SHDN or SHDN/EN }=0 \end{aligned}$ | $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ |  | 4 | 7 | $\Omega$ |
|  |  |  | $\mathrm{T}_{\text {A }}=\mathrm{T}_{\text {MIN }}$ to $\mathrm{T}_{\text {MAX }}$ |  |  | 8 |  |
| On-Resistance During Shutdown | RONSH | $\begin{aligned} & \mathrm{ICOM}_{-}=-40 \mathrm{~mA}, \\ & 0 \mathrm{~V} \leq \mathrm{V}_{\text {COM_ }} \leq 1.5 \mathrm{~V}, \\ & \text { SHDN }=\mathrm{V}_{+} \\ & (\text {MAX } 4907 / \mathrm{MAX} 4907 \mathrm{~F}) \end{aligned}$ | $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ |  | 4 | 10 | $\Omega$ |
|  |  |  | $\mathrm{T}_{\text {A }}=\mathrm{T}_{\text {MIN }}$ to $\mathrm{T}_{\text {MAX }}$ |  |  | 13 |  |
| On-Resistance Match Between Channels | $\triangle \mathrm{RON}$ | $\begin{aligned} & \mathrm{V}+=3.0 \mathrm{~V} \\ & \mathrm{I}_{+} \mathrm{COM}_{-}=-40 \mathrm{~mA}, \\ & \mathrm{VCOM}_{-}=1.5 \mathrm{~V} \text { (Note 4) } \end{aligned}$ | $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ |  | 0.7 | 1.2 | $\Omega$ |
|  |  |  | $\mathrm{T}_{\text {A }}=\mathrm{T}_{\text {MIN }}$ to $\mathrm{T}_{\text {MAX }}$ |  |  | 1.5 |  |
| On-Resistance Flatness | RFLAT (ON) | $\begin{aligned} & \mathrm{V}+=3.0 \mathrm{~V}, \mathrm{ICOM}_{-}=-40 \mathrm{~mA}, \\ & \mathrm{~V}_{\text {com }}=1.5 \mathrm{~V}, 3.0 \mathrm{~V}(\text { Note } 5) \end{aligned}$ |  | 1.0 |  |  | $\Omega$ |
| Off-Leakage Current | ICOM_(OFF) | $\begin{aligned} & \mathrm{V}_{+}=3.6 \mathrm{~V}, \mathrm{~V}_{\mathrm{COM}}^{-}=0.3 \mathrm{~V}, 3.3 \mathrm{~V} \text {; } \\ & \mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}_{-}}=3.3 \mathrm{~V}, 0.3 \mathrm{~V} \end{aligned}$ |  | -1 |  | +1 | $\mu \mathrm{A}$ |
| On-Leakage Current | ICOM_(ON) | $\begin{aligned} & \hline \mathrm{V}_{+}=3.6 \mathrm{~V}, \mathrm{~V}_{\mathrm{COM}}=0.3 \mathrm{~V}, 3.3 \mathrm{~V} \text {; } \\ & \mathrm{V}_{\text {NO_ }} \text { or } \mathrm{V}_{\text {NC_ }}=0.3 \mathrm{~V}, 3.3 \mathrm{~V} \text {, or floating } \\ & \hline \end{aligned}$ |  | -1 |  | +1 | $\mu \mathrm{A}$ |
| SWITCH AC PERFORMANCE |  |  |  |  |  |  |  |
| On-Channel -3dB Bandwidth | BW | $R_{L}=R_{S}=50 \Omega$, signal $=$ | OdBm, Figure 1 |  | 1000 |  | MHz |
| Off-Isolation | VISO | $\begin{aligned} & f=10 \mathrm{MHz} ; \mathrm{VNO}_{\mathrm{NO}_{-}}, \mathrm{V}_{\mathrm{NC}_{-}}=1 \mathrm{VP}_{\mathrm{P}-\mathrm{P} ;} \\ & \mathrm{RL}_{\mathrm{L}}=\mathrm{RS}=50 \Omega \text {, Figure } 1 \end{aligned}$ |  |  | -60 |  | dB |
|  |  | $\begin{aligned} & f=250 \mathrm{MHz} ; \mathrm{V}_{\text {NO_}}, \mathrm{V}_{\mathrm{NC}_{-}}=1 \mathrm{~V}_{\mathrm{P-P}} ; \\ & \mathrm{R}_{\mathrm{L}}=\mathrm{RS}_{\mathrm{S}}=50 \Omega \text {, Figure } 1 \end{aligned}$ |  | -32 |  |  |  |
|  |  | $\begin{aligned} & \mathrm{f}=500 \mathrm{MHz} ; \mathrm{V}_{\mathrm{NO}_{-}}, \mathrm{V}_{\mathrm{NC}_{-}}=1 \mathrm{~V}_{\mathrm{P}-\mathrm{P} ;} \\ & \mathrm{R}_{\mathrm{L}}=\mathrm{RS}_{\mathrm{S}}=50 \Omega, \text { Figure } 1 \end{aligned}$ |  | -26 |  |  |  |

## High-/Full-Speed USB 2.0 Switches

## ELECTRICAL CHARACTERISTICS (continued)

$\left(\mathrm{V}+=+3 \mathrm{~V}\right.$ to $+3.6 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=\mathrm{T}_{\mathrm{MIN}}$ to $\mathrm{T}_{\mathrm{MAX}}$, unless otherwise noted. Typical values are at $\mathrm{V}+=3.3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$.) (Note 2$)$


## High-/Full-Speed USB 2.0 Switches

## ELECTRICAL CHARACTERISTICS (continued)

$\left(\mathrm{V}+=+3 \mathrm{~V}\right.$ to $+3.6 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=\mathrm{T}_{\mathrm{MIN}}$ to $\mathrm{T}_{\mathrm{MAX}}$, unless otherwise noted. Typical values are at $\mathrm{V}+=3.3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$.) (Note 2)

| PARAMETER | SYMBOL | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Total Harmonic Distortion Plus Noise | THD + N | $\begin{aligned} & \mathrm{V}_{\text {COM_ }}=2 \mathrm{~V}_{\mathrm{P}-\mathrm{P},} \mathrm{RL}_{\mathrm{L}}=600 \Omega, \mathrm{f}=20 \mathrm{~Hz} \text { to } \\ & 20 \mathrm{kHz} \end{aligned}$ |  | 0.03 |  | \% |
| Charge Injection | Q | $V_{G E N}=1.5 \mathrm{~V}, \mathrm{R}_{\mathrm{GEN}}=0 \Omega, \mathrm{C}_{\mathrm{L}}=100 \mathrm{pF},$ Figure 6 |  | 5 |  | pC |
| SWITCH LOGIC |  |  |  |  |  |  |
| Logic-Input-Voltage Low | $\mathrm{V}_{\text {IL }}$ |  |  |  | 0.4 | V |
| Logic-Input-Voltage High | $\mathrm{V}_{\mathrm{IH}}$ |  | 1.1 |  |  | V |
| Input-Logic Hysteresis | VHYST |  |  | 100 |  | mV |
| Input Leakage Current | IIN | $\mathrm{V}+=3.6 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0$ or $\mathrm{V}+$ | -1 |  | +1 | $\mu \mathrm{A}$ |
| Operating Supply-Voltage Range | V+ |  | 3.0 |  | 3.6 | V |
| Quiescent Supply Current | I+ | $\begin{aligned} & \mathrm{V}+=3.6 \mathrm{~V}, \mathrm{~V} \text { IN }=0 \text { or } \mathrm{V}+\text {, SHDN or } \\ & \text { SHDN } / E N=0 \end{aligned}$ |  | 120 | 300 | $\mu \mathrm{A}$ |
| Quiescent Supply Current During Shutdown | I+ | $\begin{aligned} & \mathrm{V}+=3.6 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=0 \text { or } \mathrm{V}+\text {, SHDN or } \\ & \text { SHDN/EN }=\mathrm{V}_{+} \end{aligned}$ |  |  | 2 | $\mu \mathrm{A}$ |

Note 2: All units are $100 \%$ production tested at $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$. Limits over the operating temperature range are guaranteed by design and not production tested.
Note 3: The switch will turn off for voltages above (VFP); therefore, protecting downstream circuits in case of a fault condition (MAX4906F/MAX4907F).
Note 4: $\triangle \mathrm{R}_{\mathrm{ON}(\mathrm{MAX})}=\left|\mathrm{RON}_{\mathrm{ON}}(\mathrm{CH} 1)-\mathrm{RON}(\mathrm{CH} 2)\right|$
Note 5: Flatness is defined as the difference between the maximum and minimum value of on-resistance, as measured over specified analog signal ranges.
Note 6: Between any two switches.
Note 7: Switch off-capacitance, switch on-capacitance, output skew between switches, and output skew same-switch limits are not production tested; design guaranteed by bench characterization.

Typical Operating Characteristics
$\left(\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}\right.$, unless otherwise noted.)


## High-/Full-Speed USB 2.0 Switches

Typical Operating Characteristics (continued)
( $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise noted.)


## High-/Full-Speed USB 2.0 Switches

MAX4906/MAX4606F/MAX4907/MAX4907F Typical Operating Characteristics (continued) ( $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise noted.)




## High-/Full-Speed USB 2.0 Switches

Pin Description

| PIN |  | NAME | FUNCTION |
| :---: | :---: | :---: | :---: |
| MAX4906/ MAX4906F | $\begin{aligned} & \text { MAX4907I } \\ & \text { MAX4907F } \end{aligned}$ |  |  |
| 1 | 8 | IN | Digital Control Input. IN controls switch 1 and switch 2. |
| 2 | - | SHDN/EN | Shutdown and Enable Input. Drive SHDN/EN high to consume minimum current and to put the device in high-impedance mode. Drive the SHDN/ $\overline{\mathrm{EN}}$ low for normal operation. |
| 3 | 2 | GND | Ground |
| 4 | 3 | COM1 | Analog Switch 1-Common Terminal |
| 5 | 4 | COM2 | Analog Switch 2-Common Terminal |
| 6 | 5 | NO2 | Analog Switch 2-Normally Open Terminal |
| 7 | 6 | NO1 | Analog Switch 1-Normally Open Terminal |
| 8 | - | NC2 | Analog Switch 2-Normally Closed Terminal |
| 9 | - | NC1 | Analog Switch 1-Normally Closed Terminal |
| 10 | 7 | V+ | Positive-Supply Voltage Input. Connect V+ to a 3.0 V to 3.6 V supply voltage. Bypass $\mathrm{V}+$ to GND with a $0.1 \mu \mathrm{~F}$ capacitor. |
| - | 1 | SHDN | Shutdown Input. Drive SHDN high to put the device into shutdown mode. For normal operation, drive SHDN low. |

Test Circuits/Timing Diagrams


OFF-ISOLATION $=20 \log \frac{V_{\text {OUT }}}{V_{\text {IN }}}$
*FOR CROSSTALK THIS PIN IS NO2.
MEASUREMENTS ARE STANDARDIZED AGAINST SHORTS AT IC TERMINALS.
NC2 AND COM2 ARE OPEN.
OFF-ISOLATION IS MEASURED BETWEEN COM_ AND "OFF" NO_ OR NC_ TERMINAL ON EACH SWITCH.
ON-LOSS IS MEASURED BETWEEN COM_ AND "ON" NO_OR NC_ TERMINAL ON EACH SWITCH.
CROSSTALK IS MEASURED FROM ONE CHANNEL TO THE OTHER CHANNEL.
SIGNAL DIRECTION THROUGH SWITCH IS REVERSED; WORST VALUES ARE RECORDED.

Figure 1. On-Loss, Off-Isolation, and Crosstalk

## High-/Full-Speed USB 2.0 Switches



Figure 2. Channel Off/On-Capacitance


Figure 3. Switching Time

## High-/Full-Speed USB 2.0 Switches



MAX4906/MAX4606F/MAX4907/MAX4907F

Figure 4. Output Signal Skew, Rise/Fall Time, Propagation Delay

## High-/Full-Speed USB 2.0 Switches



Figure 5. MAX4906F/MAX4907F Fault-Protection Response/Recovery Time


Figure 6. Charge Injection

## Detailed Description

The MAX4906/MAX4906F/MAX4907/MAX4907F analog switches are targeted for USB 2.0 high-speed (480Mbps) switching applications. These devices still meet USB low- and full-speed requirements and are suitable for 10/100 Ethernet switching. The MAX4906/ MAX4906F feature two SPDT switches, while the MAX4907/MAX4907F feature two SPST switches. The MAX4907/MAX4907F switch configurations have a low $7 \Omega$ (max) on-resistance and 7 pF (max) on-capacitance.

The MAX4906/MAX4906F/MAX4907/MAX4907F are fully specified to operate from a single +3.0 V to +3.6 V supply and are available with +5.5 V fault protection (MAX4906F/ MAX4907F). When operating from $\mathrm{a}+3.0 \mathrm{~V}$ to +3.6 V supply, the low threshold of these devices permits them to be used with logic levels as low as 1.4V.The MAX4906/MAX4906F/MAX4907/MAX4907F are based on a charge-pump-assisted n-channel architecture and thus operate at $300 \mu \mathrm{~A}$ (max) quiescent current. These devices all feature a shutdown input to reduce the quiescent current to less than $2 \mu \mathrm{~A}$ (max).

## High-/Full-Speed USB 2.0 Switches

Functional Diagram/Truth Table


## Digital Control Input

The MAX4906/MAX4906F/MAX4907/MAX4907F provide a single-digit control logic input, IN. IN controls the position of the switches as shown in the Functional Diagram/Truth Table. Driving IN rail-to-rail minimizes power consumption. With a +3.0 V to +3.6 V supply voltage range, these devices are +1.4 V logic compatible.

## Analog Signal Levels

The on-resistance of the MAX4906/MAX4906F/ MAX4907/MAX4907F is very low and stable as the analog input signals are swept from ground to $V+$ (see the Typical Operating Characteristics). These switches are bidirectional, allowing $\mathrm{NO}_{-}$, NC_, and COM_ to be configured as either inputs or outputs.

## Overvoltage Fault Protection

The MAX4906F and MAX4907F feature +5.5 V fault protection to COM1 and COM2. Fault protection prevents these switches from being damaged due to shorts to the USB bus voltage rail.

## Shutdown Mode

The MAX4906/MAX4906F feature a shutdown mode that reduces the quiescent current supply to less than $2 \mu \mathrm{~A}$. Drive SHDN/EN high to place the devices in highimpedance mode. When SHDN/EN is driven low, the devices are normal in operation.
The MAX4907/MAX4907F feature a SHDN input that reduces the quiescent current supply to less than $2 \mu \mathrm{~A}$. Drive SHDN high to place the devices in low current mode. The devices can be used in low current mode, but with a reduced analog voltage range of $0<V_{\text {ANALOG }}<$ 1.5 V and reduced performance. When SHDN is driven low, the MAX4907/MAX4907F are in normal operation.

## Applications Information

USB Switching
The MAX4906/MAX4906F/MAX4907/MAX4907F analog switches are fully compliant with the USB 2.0 specification. The low on-resistance and low on-capacitance of these switches make them ideal for high-performance switching applications. The MAX4906/MAX4906F are

## High-/Full-Speed USB 2.0 Switches



Figure 7. MAX4906/MAX4906F USB Data Routing


Figure 8. MAX4906/MAX4906F Switching Between Multiple USB Hosts
ideal for routing USB data lines (see Figure 7) and for applications that require switching between multiple USB hosts (see Figure 8). The MAX4907/MAX4907F can be used in applications that require different data types to share the same pins (see Figure 9); however, the shared device must be capable of going into the tristate mode. The MAX4906F/MAX4907F also feature +5.5 V fault protection to guard systems against shorts to the USB bus voltage. The fault-protected versions are recommended for all USB applications.


Figure 9. MAX4907/MAX4907F USB/SPI/GPIO Switch
Ethernet Switching
The wide bandwidth of the MAX4906/MAX4906F/ MAX4907/MAX4907F meets the needs of 10/100 Ethernet switching. These devices switch the signals from two interface transformers and connect the signals to a single 10/100 Base-T Ethernet PHY, simplifying docking station design and reducing manufacturing costs.

Power-Supply Sequencing Caution: Do not exceed the absolute maximum ratings because stresses beyond the listed ratings may cause permanent damage to the device.
Proper power-supply sequencing is recommended for all CMOS devices. Always apply V+ before applying analog signals, especially if the analog signal is not current limited.

## Layout

High-speed switches require proper layout and design procedures for optimum performance. Keep design-controlled-impedance PC board traces as short as possible. Ensure that bypass capacitors are as close to the device as possible. Use large ground planes where possible.

## High-/Full-Speed USB 2.0 Switches



| PART | CONFIGURATION | FAULT <br> PROTECTION | TOP <br> MARK |
| :--- | :---: | :---: | :---: |
| MAX4906ELB | Dual SPDT | NO | AAB |
| MAX4906FELB | Dual SPDT | YES | AAA |
| MAX4907ELA | Dual SPST | NO | AAE |
| MAX4907FELA | Dual SPST | YES | AAD |

Chip Information
PROCESS: BiCMOS

## Revision History

Pages changed at Rev 2: 1, 2, 3, 7, 11, 14

## High-/Full-Speed USB 2.0 Switches

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to www.maxim-ic.com/packages.)


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